High-current gain Power Transistor (-60V, -3A)

- 1) High DC current gain. (Typ.440 at VcE/Ic=-4V/-0.5A)
- 2) Low $V_{CE(sat)}$. (Typ.-0.2V at Ic/IB=-2/-0.05A)
- 3) Complements the 2SD1944.

●Packaging specifications and hre

Туре	2SB1639
Package	TO-220FN
hre	н
Code	_
Basic ordering unit (pieces)	500

●Absolute maximum ratings(Ta=25℃)

Parameter	Symbol	Limits	. Unit	
Collector-base voltage	Vcво	-60	٧	
Collector-emitter voltage	VCED	-60	V	
Emitter-base voltage	VEBO	6	٧	
Collector current	I c	-3	Α	
Collector power dissipation		2	w	
	Pc	30	W(Tc=25℃)	
Junction temperature	Tj	150	τ	
Storage temperature	Tetg	−55~150	°	

●Electrical characteristics (Ta=25℃)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVcEo	-60	_	_	V	lc=-1mA
Collector-base breakdown voltage	BVcao	-60	_	_	V	Ic=-50 μA
Emitter-base breakdown voltage	ВУево	-6		_	٧	Iε=-50 μ A
Collector cutoff current	lcto		<u> </u>	-10	μΑ	Vce=-60V
Emitter cutoff current	leso.			10	μA	V _{EB} =6V
Collector-emitter saturation voltage	VCE(sat)	_	_	-1	V	Ic/Is=-1V/-0.05A
DC current transfer ratio	hec	400	_	800		Vce=-4V , Ic=-0.5A
Transition frequency	fτ	_	60	_	MHz	Voe=-5V , 1e=-0.5A , t=30MHz
Output capacitance	Cab	-	80	_	рF	Vce=-10V, ie=0A, f=1MHz

(SPEC-B302)

High-current gain Power Transistor (60V, 3A) 2SD2318/2SD1944

●Features

- 1) High DC current gain.
- 2) Low VoE(set). (Typ. 0.5V at lc/ls=2/0.5A)
- 3) Complements the 2SB1639.

●Packaging specifications and hre

2SD2318	2SD1944
CPT3	TO-220FP
UV	HJK
TL	
2500	500
	CPT3 UV TL

●Absolute maximum ratings (Ta=25℃)

Parameter		Symbol	Limits	Unit		
Collector-base voltage		Vœ	80	V		
Collector-emitter voltage		Vceo	60	V		
Emitter-base voite	r-base voltage V _{EBO}		6	V		
Collector current		1.	3	Α		
		lc lc	4.5	A (Pulse) *		
Collector power dissipation	2SD2318		1	w		
		ا ہا	15	W (Tc=25°C)		
	2SD1944	Pc	2	W		
			30	W (Tc=28°C)		
Junction tempera	ture	Tj	150 °C			
Storage temperal	torage temperature		-55~150	°C		

^{*} Sigle pulse Pw=100ms

●Electrical characteristics (Ta=25℃)

Parameter		Symbol	Min.	Тур.	Мах.	Unit	Conditions	
Collector-base breakdow	n voltage	ВУсво	80	_	_	V	lc=50 μ A	
Collector-emitter breakdown voltage		BVceo	60	_		V	Ic=1mA	
Emitter-base breakdown voltage		BVeso	6		_	ν	Iε=50 μ A	
Collector cutoff current		Iceo	_	_	100	μA	V _{CB} =80V	
Emitter cutoff current		ГЕВО			100	μΑ	VES=6V	
Collector-emitter saturation	on voltage	VCE(set)	_	_	1.0	V	lc/ls=2A/0.05A	
Base-emitter saturation v	oltage	VBE(ent)	_	_	1.5	V	Ic/Is=2A/0.05A	
DC current transfer ratio	2SD2318		560	_	1800	_	V 0.00 E1	
	DC current transfer ratio	2SD1944	hre	400	_	2000	_	Vce/lc=4V/0.5A
Transition frequency		f⊤	-	50	_	MHz	Vc=5V , l=-0.2A , f=10MHz	*
Output capacitance	Output capacitance			60	_	pF	Vcs=10V , Is=0A , I=1MHz	

^{*} Measured using pulse current.

(96-244-D302)

Notes

- The contents described in this catalogue are correct as of March 1997.
- No unauthorized transmission or reproduction of this book, either in whole or in part, is permitted.
- The contents of this book are subject to change without notice. Always verify before use that the contents are the latest specifications. If, by any chance, a defect should arise in the equipment as a result of use without verification of the specifications, ROHM CO., LTD., can bear no responsibility whatsoever.
- Application circuit diagrams and circuit constants contained in this data book are shown as examples of standard use and operation. When designing for mass production, please pay careful attention to peripheral conditions.
- Any and all data, including, but not limited to application circuit diagrams, information, and various data, described in this catalogue are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO., LTD., disclaims any warranty that any use of such device shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes absolutely no liability in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices; other than for the buyer's right to use such devices itself, resell or otherwise dispose of the same; no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by ROHM CO., LTD., is granted to any such buyer.

The products listed in this catalogue are designed to be used with ordinary electronic equipment or devices (such as audio-visual equipment, office-automation equipment, communications devices, electrical appliances, and electronic toys). Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers, or other safety devices) please be sure to consult with our sales representatives in advance.

Notes when exporting

- It is essential to obtain export permission when exporting any of the above products when it falls under the category of strategic material (or labor) as determined by foreign exchange or foreign trade control laws.
- Please be sure to consult with our sales representatives to ascertain whether any product is classified as a strategic material.